NSN 5961-01-359-3338

Diode Semiconductor Device - Page 1 of 1



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Inclosure Material:
Ceramic or glass or metal
Overall Length:
Between 0.340 inches and 0.400 inches
Terminal Length:
1.000 inches
Overall Diameter:
0.185 inches
Mounting Method:
Terminal
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
7500.0 working peak reverse voltage
Current Rating Per Characteristic:
0.50 amperes forward current, average absolute and 25.00 amperes forward current, average preset
Maximum Operating Tempurature Per Measurement Point:
175.0 degrees celsius junction
Terminal Type And Quantity:
2 uninsulated wire lead
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0